



**Surface Mount Schottky Barrier Rectifier**

Reverse Voltage - 20 to 200 V

Forward Current - 1.0 A

**FEATURES**

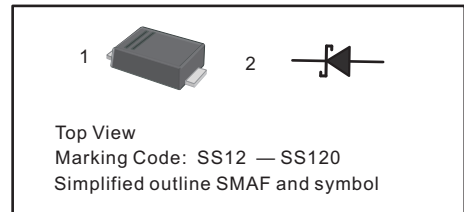
- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

**MECHANICAL DATA**

- Case: SMAF
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 27mg/0.00095oz

**PINNING**

PIN	DESCRIPTION
1	Cathode
2	Anode



**Absolute Maximum Ratings and Electrical characteristics**

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

Parameter	Symbols	SS12F	SS14F	SS16F	SS18F	SS110F	SS112F	SS115F	SS120F	Units
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	20	40	60	80	100	120	150	200	V
Maximum RMS voltage	$V_{RMS}$	14	28	42	56	70	84	105	140	V
Maximum DC Blocking Voltage	$V_{DC}$	20	40	60	80	100	120	150	200	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	1.0								A
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	$I_{FSM}$	25								A
Max Instantaneous Forward Voltage at 1 A	$V_F$	0.55	0.70		0.85		0.90			V
Maximum DC Reverse Current $T_a = 25^\circ\text{C}$ at Rated DC Reverse Voltage $T_a = 100^\circ\text{C}$	$I_R$	0.3			0.2		0.1			mA
		10			5		2			
Typical Junction Capacitance <sup>(1)</sup>	$C_j$	110	80							pF
Typical Thermal Resistance <sup>(2)</sup>	$R_{\theta JA}$	95								°C/W
Operating Junction Temperature Range	$T_j$	-55 ~ +125								°C
Storage Temperature Range	$T_{stg}$	-55 ~ +150								°C

( 1 ) Measured at 1 MHz and applied reverse voltage of 4 V D.C

( 2 ) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.



Fig.1 Forward Current Derating Curve

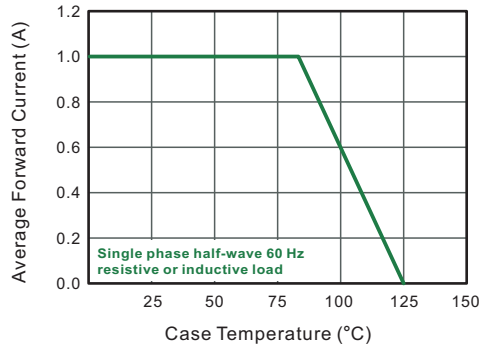


Fig.2 Typical Reverse Characteristics

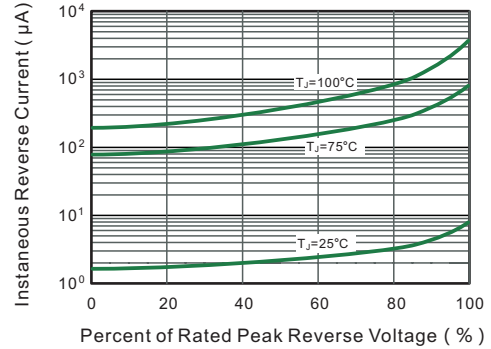


Fig.3 Typical Forward Characteristic

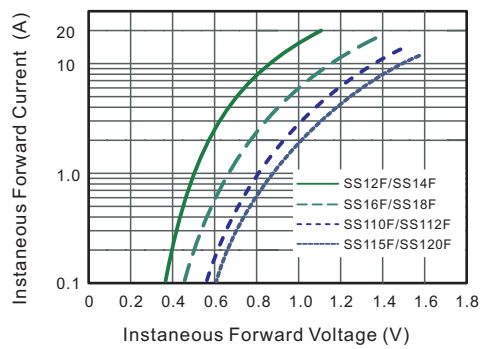


Fig.4 Typical Junction Capacitance

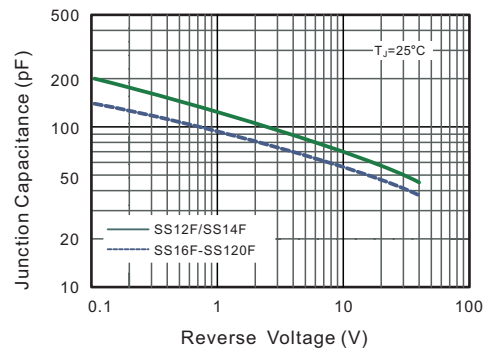


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

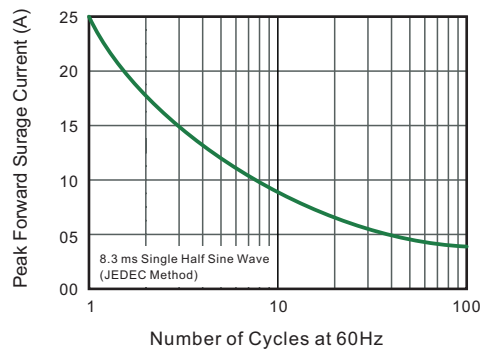
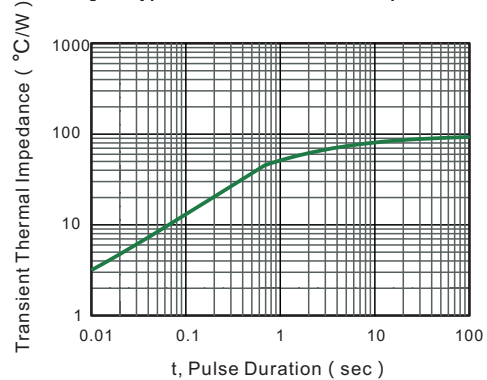


Fig.6- Typical Transient Thermal Impedance





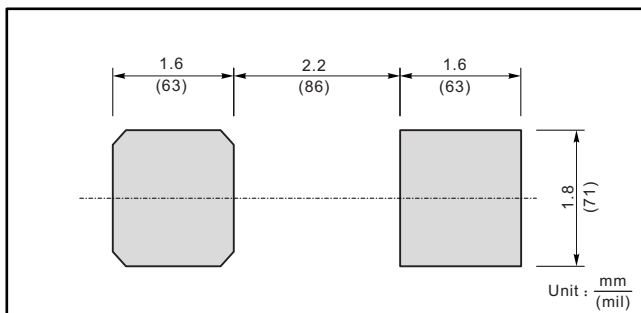
**PACKAGE OUTLINE**

Plastic surface mounted package; 2 leads

SMAF



**The recommended mounting pad size**



**Marking**

Type number	Marking code
SS12F	SS12
SS14F	SS14
SS16F	SS16
SS18F	SS18
SS110F	SS110
SS112F	SS112
SS115F	SS115
SS120F	SS120

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